

Isc N-Channel MOSFET Transistor

IRF630NL

• FEATURES

- With TO-262 packaging
- High speed switching
- Low gate input resistance
- Standard level gate drive
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

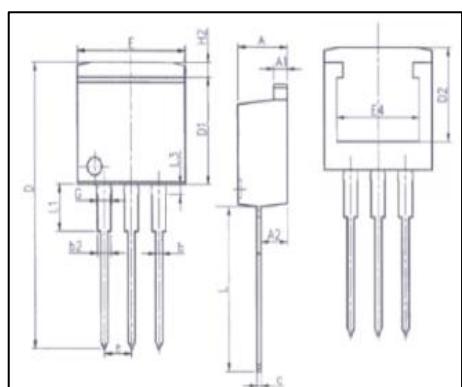
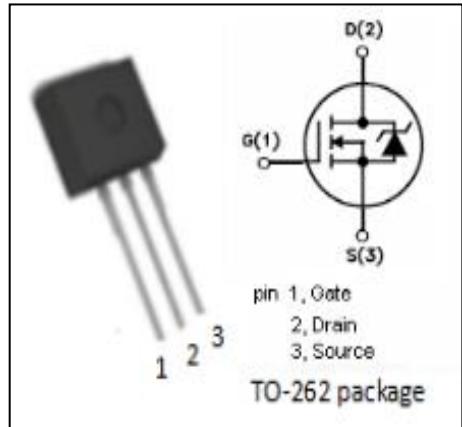
- Power supply
- Switching applications

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	200	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	9.3	A
P_D	Total Dissipation @ $T_c=25^\circ\text{C}$	82	W
T_j	Max. Operating Junction Temperature	-55~175	°C
T_{stg}	Storage Temperature	-55~175	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Channel-to-case thermal resistance	1.83	°C/W



DIM	mm	
	MIN	MAX
A	4.37	4.77
A1	1.22	1.42
A2	2.47	2.87
b	0.70	0.97
b2	1.17	1.42
c	0.28	0.53
D	23.20	24.02
D1	8.38	8.90
D2	6.00	—
E	9.90	10.39
E4	7.30	—
e	2.54 BSC	—
G	1.25	1.50
H2	—	1.31
L	13.34	14.10
L1	3.30	4.06
L3	0.95	1.15

Isc N-Channel MOSFET Transistor**IRF630NL****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{I}_D= 250\mu\text{A}$	200			V
$\text{V}_{\text{GS(th)}}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}; \text{I}_D= 250\mu\text{A}$	2		4	V
$\text{R}_{\text{DS(on)}}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}= 10\text{V}; \text{I}_D= 5.4\text{A}$			300	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$\text{V}_{\text{GS}}= \pm 20\text{V}; \text{V}_{\text{DS}}= 0\text{V}$			± 100	nA
I_{DSS}	Drain-Source Leakage Current	$\text{V}_{\text{DS}}= 200\text{V}; \text{V}_{\text{GS}}= 0\text{V}$			25	μA
V_{SD}	Diode forward voltage	$\text{I}_S= 5.4\text{A}, \text{V}_{\text{GS}} = 0\text{V}$			1.3	V

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